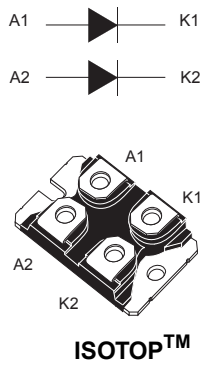


45 V power Schottky rectifier



Features

- Very small conduction losses
- Extremely fast switching
- Low thermal resistance
- Insulated package ISOTOP™:
 - Insulated voltage: 2500 V_{RMS} sine
- Avalanche capability
- ECOPACK®2 compliant

Applications

- Switching diode
- DC/DC converter
- Industrial
- Heavy duty application

Description

Dual power Schottky rectifier suited for SMPS and high frequency DC to DC converters.

Packaged in ISOTOP™, the **STPS24045** is especially intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

Note: ISOTOP™ is an ST trademark

Product status link

[STPS24045](#)

Product summary

I_{F(AV)}	2 x 120 A
V_{RRM}	45 V
V_F (typ.)	0.52 V
T_j (max.)	150 °C

1 Characteristics

Table 1. Absolute ratings (limiting values, per diode at $T_{amb} = 25\text{ °C}$, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			45	V
I _{F(RMS)}	Forward rms current			170	A
I _{F(AV)}	Average forward current, δ = 0.5, square wave	T _C = 80 °C	Per diode	120	A
		T _C = 70 °C	Per device	240	
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal		1500	A
P _{ARM}	Repetitive peak avalanche power	t _p = 10 μs, T _j = 125 °C		3096	W
T _{stg}	Storage temperature range			-55 to +150	°C
T _j	Maximum operating junction temperature ⁽¹⁾			150	°C

1. $(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

Symbol	Parameter		Max. value	Unit
$R_{th(j-c)}$	Junction to case	Per diode	0.65	°C/W
		Total	0.38	
$R_{th(c)}$	Coupling		0.10	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j (\text{diode1}) = P_{(\text{diode1})} \times R_{th(j-c)} (\text{per diode}) + P_{(\text{diode2})} \times R_{th(c)}$$

For more information, please refer to the following application note:

- AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I_R ⁽¹⁾	Reverse leakage current	$T_j = 25\text{ °C}$	$V_R = V_{RRM}$	-		2	mA
		$T_j = 125\text{ °C}$		-		300	
V_F ⁽²⁾	Forward voltage drop	$T_j = 25\text{ °C}$	$I_F = 240\text{ A}$	-		0.91	V
		$T_j = 125\text{ °C}$		-	0.72	0.87	
		$T_j = 125\text{ °C}$	$I_F = 120\text{ A}$	-	0.52	0.67	

1. Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$

2. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the maximum conduction losses, use the following equation:

$$P = 0.47 \times I_{F(AV)} + 0.00167 \times I_F^2 (\text{RMS})$$

For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

1.1 Characteristics (curves)

Figure 1. Conduction losses versus average forward current (per diode)

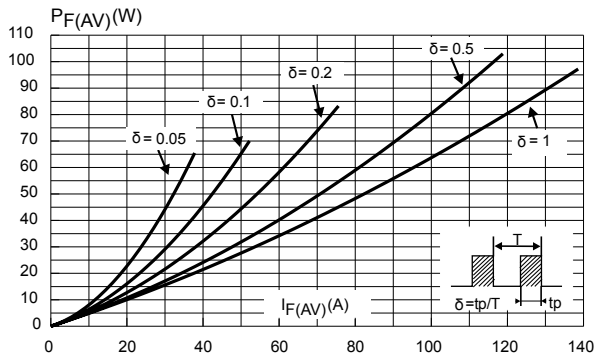


Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

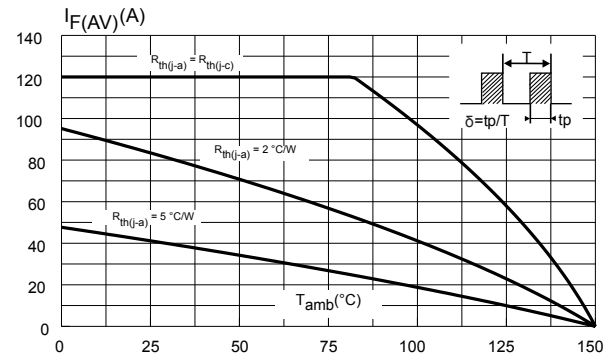


Figure 3. Normalized avalanche power derating versus pulse duration ($T_j = 125\text{ °C}$)

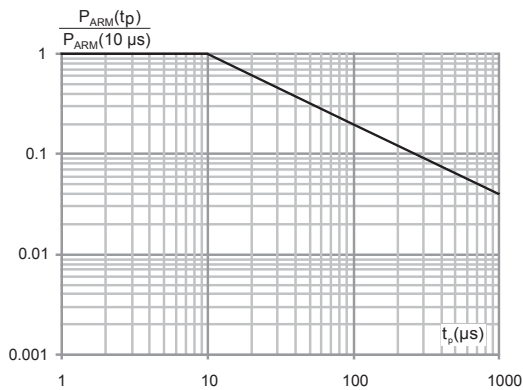


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration

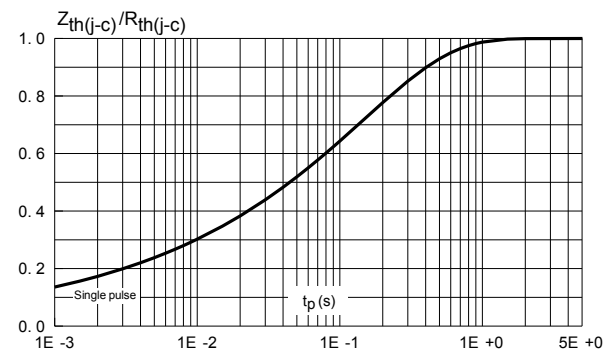


Figure 5. Reverse leakage current versus reverse voltage applied (typical values per diode)

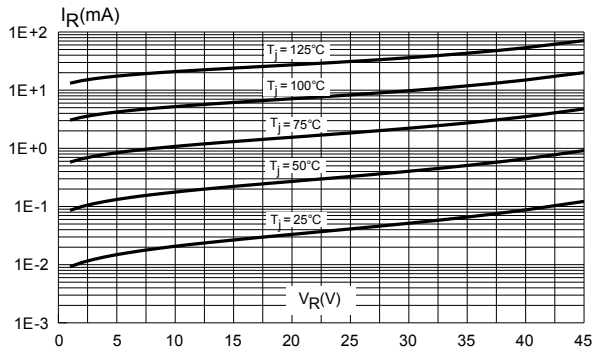


Figure 6. Junction capacitances versus reverse voltage applied (typical values per diode)

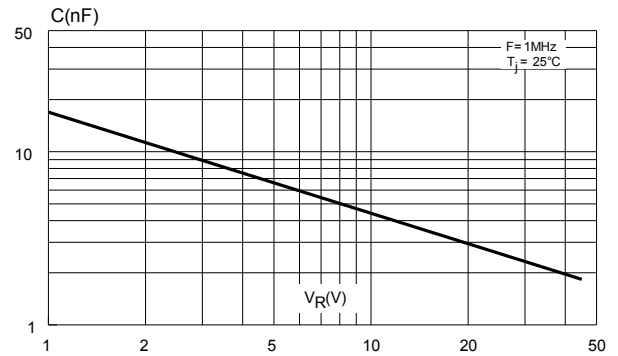
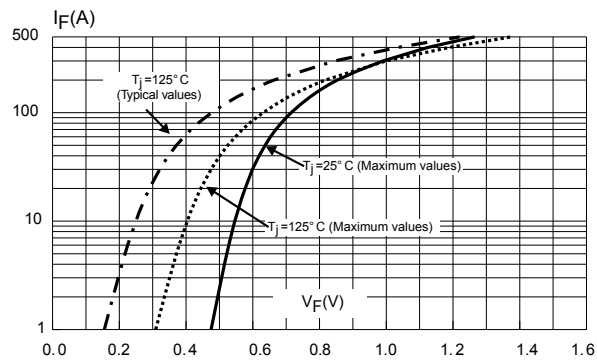


Figure 7. Forward voltage drop versus forward current (per diode)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 ISOTOP™ package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 1.3 N·m
- Maximum torque value: 1.5 N·m

STMicroelectronics strongly recommend the use of the screws delivered with this product.
The use of any other screws is entirely at the user's own risk and will invalidate the warranty.

Figure 8. ISOTOP™ package outline

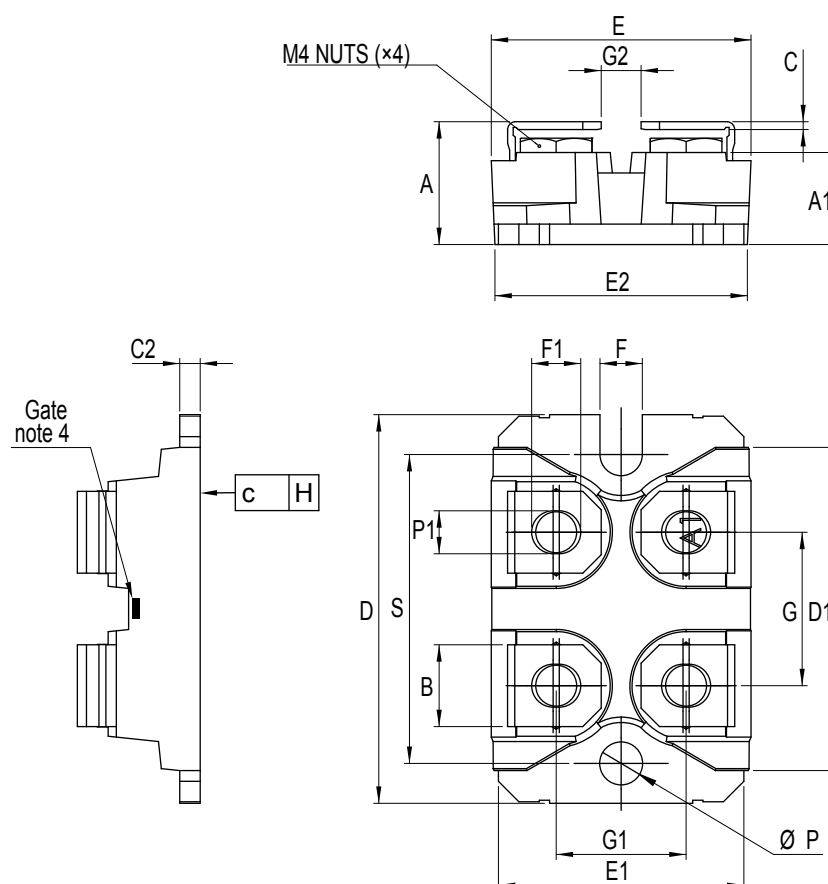


Table 4. ISOTOP™ package mechanical data

Ref.	Dimensions			
	Millimeters		Inches ⁽¹⁾	
	Min.	Max.	Min.	Max.
A	11.80	12.20	0.460	0.480
A1	8.90	9.10	0.350	0.358
B	7.80	8.20	0.307	0.323
C	0.75	0.85	0.030	0.033
C2	1.95	2.05	0.077	0.081
D	37.80	38.20	1.488	1.504
D1	31.50	31.70	1.240	1.248
E	25.15	25.50	0.990	1.004
E1	23.85	24.15	0.939	0.951
E2	24.80		0.976	
G	14.90	15.10	0.587	0.594
G1	12.60	12.80	0.496	0.504
G2	3.50	4.30	0.138	0.169
F	4.10	4.30	0.161	0.169
F1	4.60	5.00	0.181	0.197
H	-0.05	0.10	-0.002	0.004
Diam P	4.00	4.30	0.157	0.169
P1	4.00	4.40	0.157	0.173
S	30.10	30.30	1.185	1.193

1. Inches given for reference only

3 Ordering information

Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS24045TV	STPS24045TV	ISOTOP™	27 g without screws	10 with screws	Tube

Revision history

Table 6. Document revision history

Date	Version	Changes
July-2003	3	Previous release.
17-Sep-2018	4	Updated cover page. Updated Table 1. Absolute ratings (limiting values, per diode at $T_{amb} = 25\text{ °C}$, unless otherwise specified) and Table 5. Ordering information. Removed figure 3, figure 4 and figure 5. Minor text changes to improve readability.

IMPORTANT NOTICE – PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2018 STMicroelectronics – All rights reserved

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9